



HLB124E

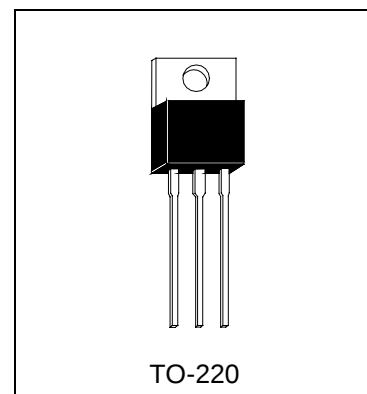
NPN EPITAXIAL PLANAR TRANSISTOR

Description

The HLB124E is designed for high voltage, high speed switching inductive circuits, and amplifier applications.

Features

- High Speed Switching
- Low Saturation Voltage
- High Reliability



Absolute Maximum Ratings (Ta=25°C)

- Maximum Temperatures
Storage Temperature -55 ~ +150 °C
Junction Temperature +150 °C
- Maximum Power Dissipation
Total Power Dissipation (Tc=25°C)..... 35 W
- Maximum Voltages and Currents (Ta=25°C)
BVCBO Collector to Base Voltage 600 V
BVCEO Collector to Emitter Voltage 400 V
BVEBO Emitter to Base Voltage 8 V
IC Collector Current (DC)..... 2 A
IC Collector Current (Pulse)..... 4 A
IB Base Current (DC)..... 1 A
IB Base Current (Pulse)..... 2 A

Characteristics (Ta=25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BVCBO	600	-	-	V	IC=1mA
BVCEO	400	-	-	V	IC=10mA
BVEBO	8	-	-	V	IE=1mA
ICBO	-	-	10	uA	VCB=600V
IEBO	-	-	10	uA	VEB=9V, IC=0
*VCE(sat)1	-	-	0.3	V	IC=0.1A, IB=10mA
*VCE(sat)2	-	-	0.8	V	IC=0.3A, IB=30mA
*VBE(sat)1	-	-	0.9	V	IC=0.1A, IB=10mA
*VBE(sat)2	-	-	1.2	V	IC=0.3A, IB=30mA
*hFE1	10	-	40		VCE=5V, IC=0.3A
*hFE2	10	-	-		VCE=5V, IC=0.5A
*hFE3	6	-	-		VCE=5V, IC=1A
fT	15	-	-	MHz	VCE=10V, IC=0.3, f=1MHz

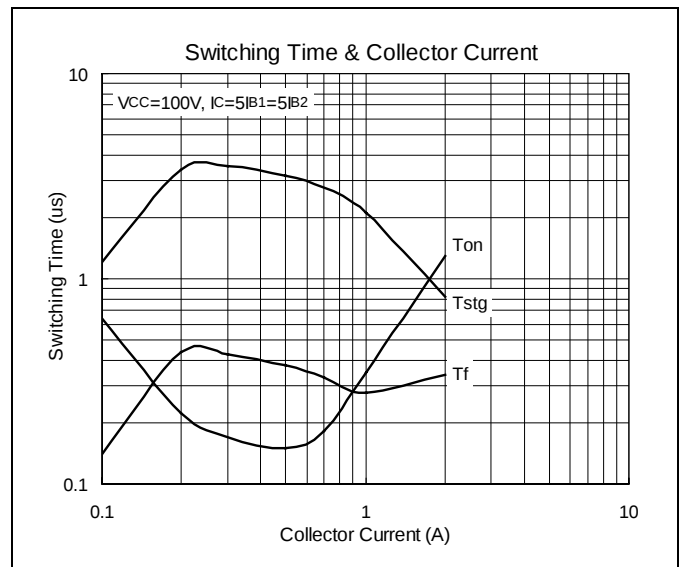
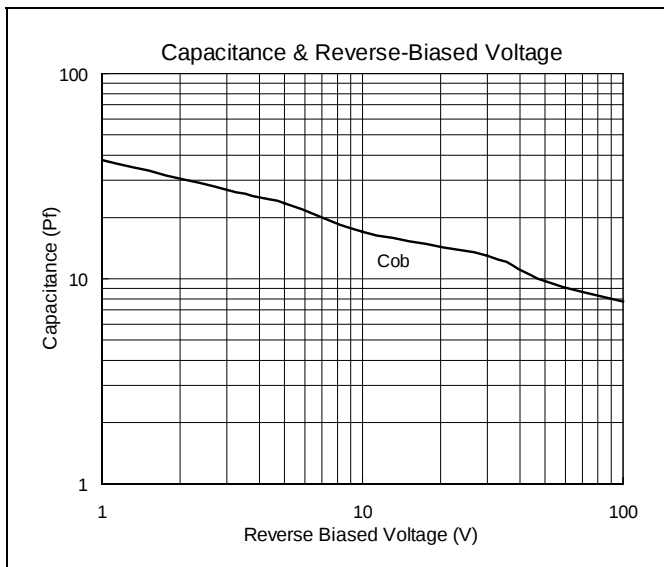
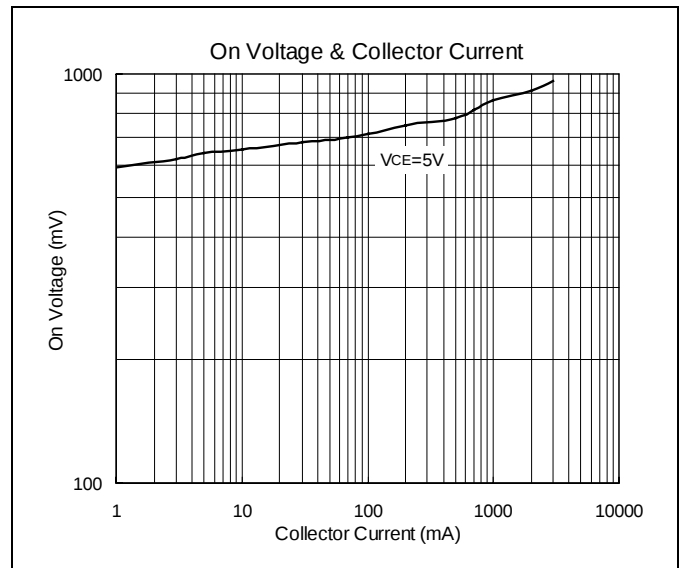
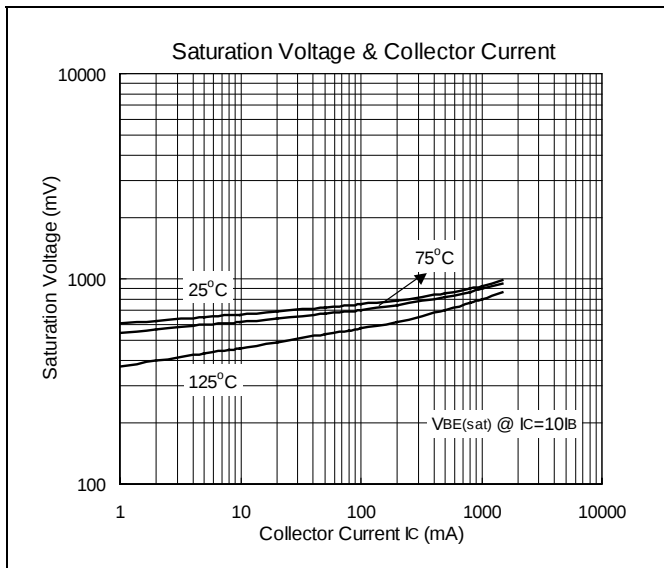
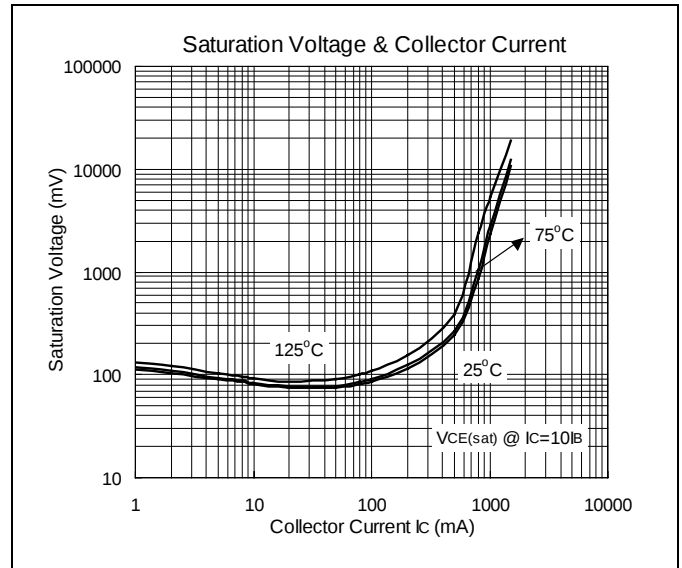
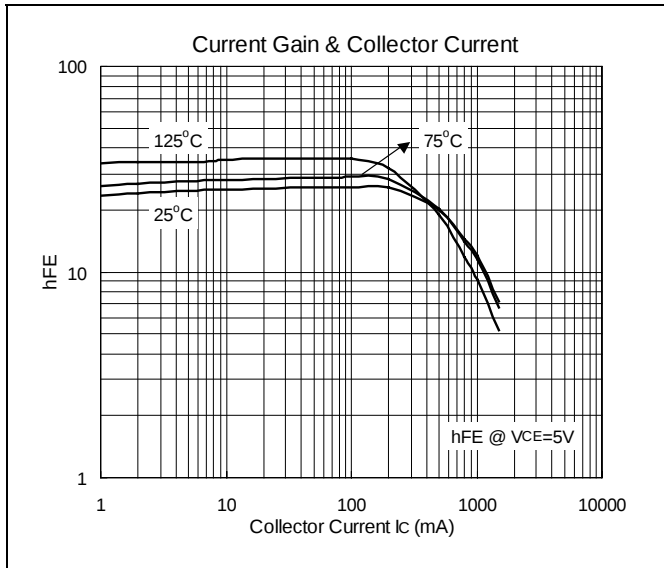
*Pulse Test : Pulse Width ≤380us, Duty Cycle≤2%

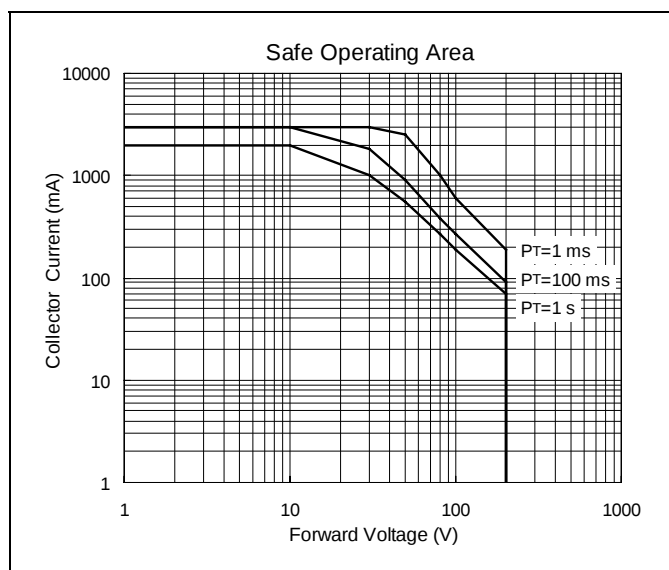
Classification of hFE1

Rank	B1	B2	B3	B4	B5	B6
Range	10~17	13~22	18~27	23~32	28~37	33~40



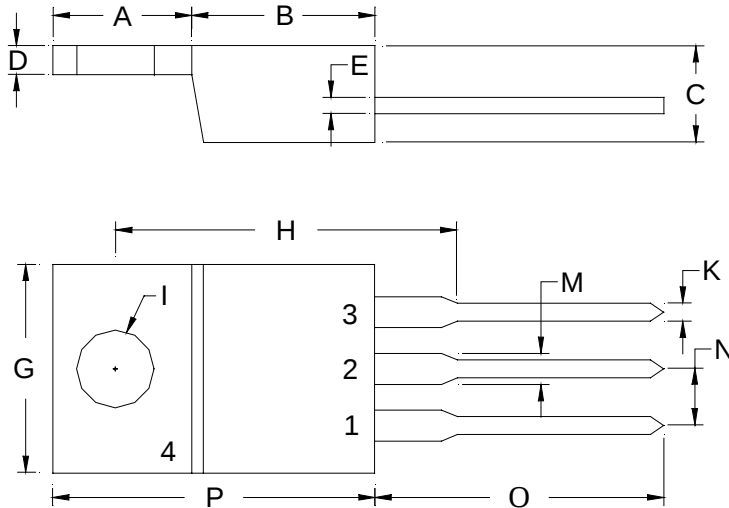
Characteristics Curve





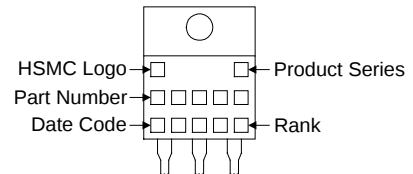


TO-220AB Dimension



3-Lead TO-220AB Plastic Package
HSMC Package Code: E

Marking:



Style: Pin 1.Base 2.Collector 3.Emitter

*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.2197	0.2949	5.58	7.49	I	-	*0.1508	-	*3.83
B	0.3299	0.3504	8.38	8.90	K	0.0295	0.0374	0.75	0.95
C	0.1732	0.185	4.40	4.70	M	0.0449	0.0551	1.14	1.40
D	0.0453	0.0547	1.15	1.39	N	-	*0.1000	-	*2.54
E	0.0138	0.0236	0.35	0.60	O	0.5000	0.5618	12.70	14.27
G	0.3803	0.4047	9.66	10.28	P	0.5701	0.6248	14.48	15.87
H	-	*0.6398	-	*16.25					

Notes: 1.Dimension and tolerance based on our Spec. dated Sep. 07,1997.

2.Controlling dimension: millimeters.

3.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.

4.If there is any question with packing specification or packing method, please contact your local HSMC sales office.

Material:

- Lead: 42 Alloy; solder plating
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

Important Notice:

- All rights are reserved. Reproduction in whole or in part is prohibited without the prior written approval of HSMC.
- HSMC reserves the right to make changes to its products without notice.
- **HSMC semiconductor products are not warranted to be suitable for use in Life-Support Applications, or systems.**
- HSMC assumes no liability for any consequence of customer product design, infringement of patents, or application assistance.

Head Office And Factory:

- **Head Office** (Hi-Sincerity Microelectronics Corp.) : 10F.,No. 61, Sec. 2, Chung-Shan N. Rd. Taipei Taiwan R.O.C.
Tel: 886-2-25212056 Fax: 886-2-25632712, 25368454
- **Factory 1:** No. 38, Kuang Fu S. Rd., Fu-Kou Hsin-Chu Industrial Park Hsin-Chu Taiwan. R.O.C
Tel: 886-3-5983621~5 Fax: 886-3-5982931